P-Channel 20-V (D-S) MOSFET

CHARACTERISTICS

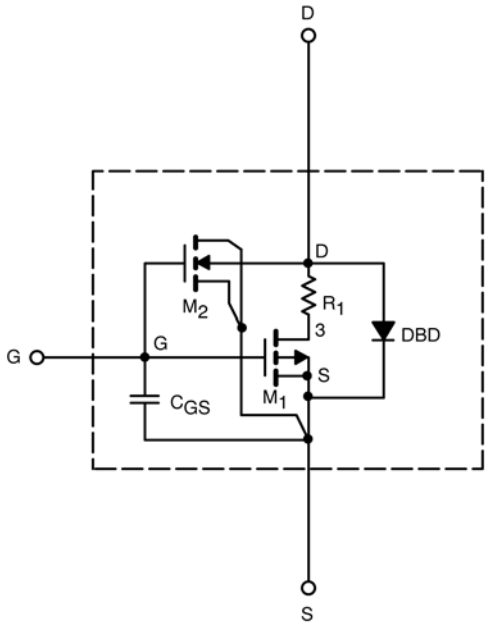
- P-Channel Vertical DMOS
- Macro Model (Subcircuit Model)
- Level 3 MOS
- Apply for both Linear and Switching Application
- Accurate over the −55 to 125°C Temperature Range
- Model the Gate Charge, Transient, and Diode Reverse Recovery Characteristics

DESCRIPTION

The attached spice model describes the typical electrical characteristics of the p-channel vertical DMOS. The subcircuit model is extracted and optimized over the −55 to 125°C temperature ranges under the pulsed 0-V to 5-V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

SUBCIRCUIT MODEL SCHEMATIC

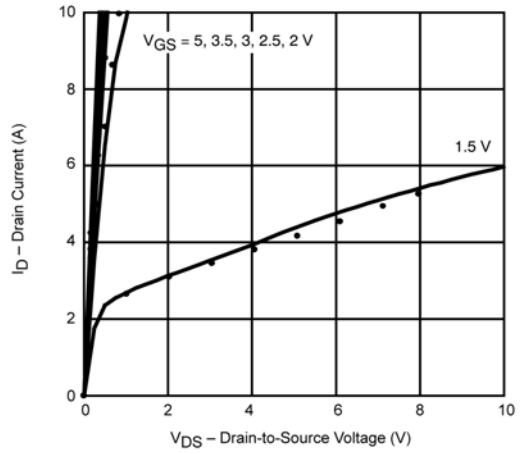


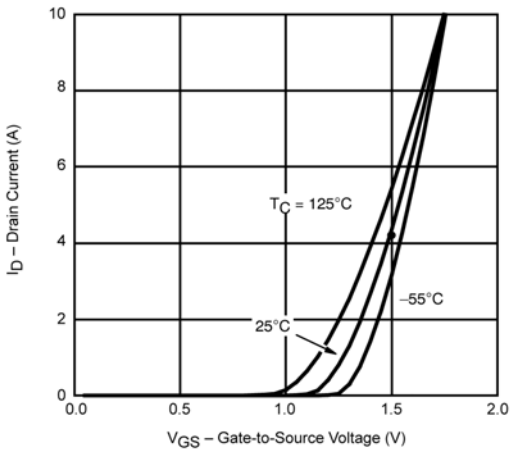
This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.

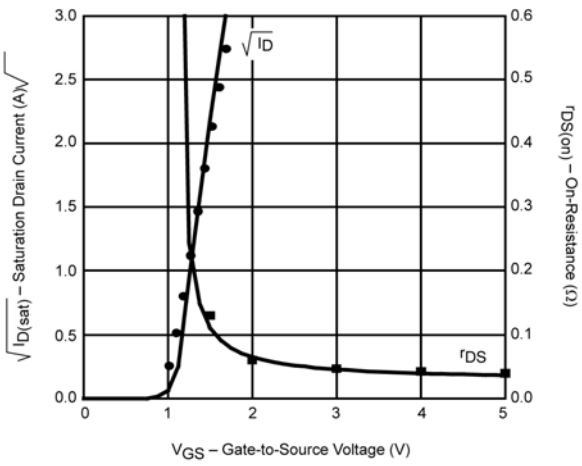
SPECIFICATIONS (T_J = 25°C UNLESS OTHERWISE NOTED)					
Parameter	**Symbol**	**Test Condition**	**Simulated Data**	**Measured Data**	**Unit**
Static					
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = –250 μA	0.87	0.90	V
On-State Drain Current[a]	$I_{D(on)}$	V_{DS} ≤ –5 V, V_{GS} = –4.5 V	52		A
Drain-Source On-State Resistance[a]	$r_{DS(on)}$	V_{GS} = –4.5 V, I_D = –1 A	0.056	0.057	Ω
		V_{GS} = –2.5 V, I_D = –1 A	0.081	0.080	
Forward Transconductance[a]	g_{fs}	V_{DS} = –10 V, I_D = –1 A	6	6	S
Diode Forward Voltage[a]	V_{SD}	I_S = –1 A, V_{GS} = 0 V	–0.72	–0.73	V
Dynamic[b]					
Total Gate Charge	Q_g	V_{DS} = –10 V, V_{GS} = –4.5 V, I_D = –1 A	9.9	11	nC
Gate-Source Charge	Q_{gs}		2.1	2.1	
Gate-Drain Charge	Q_{gd}		2.9	2.9	
Turn-On Delay Time	$t_{d(on)}$	V_{DD} = –10 V, R_L = 10 Ω I_D ≅ –1 A, V_{GEN} = –4.5 V, R_G = 6 Ω	24	17	ns
Rise Time	t_r		33	28	
Turn-Off Delay Time	$t_{d(off)}$		49	88	
Fall Time	t_f		62	60	
Source-Drain Reverse Recovery Time	t_{rr}	I_F = –1 A, di/dt = 100 A/μs	39		

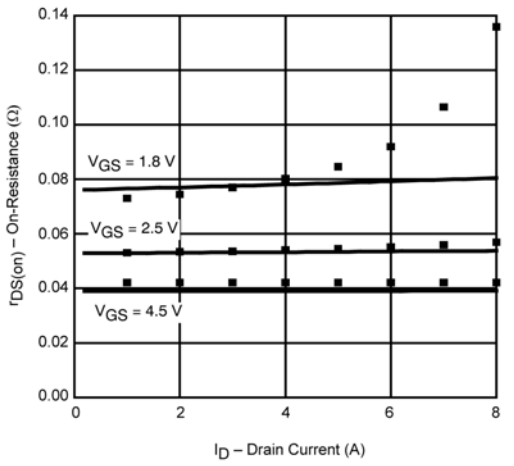
Notes
a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2%.
b. Guaranteed by design, not subject to production testing.

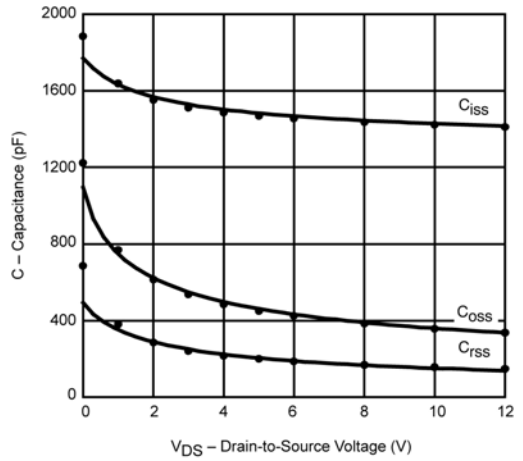
COMPARISON OF MODEL WITH MEASURED DATA (T_J=25°C UNLESS OTHERWISE NOTED)

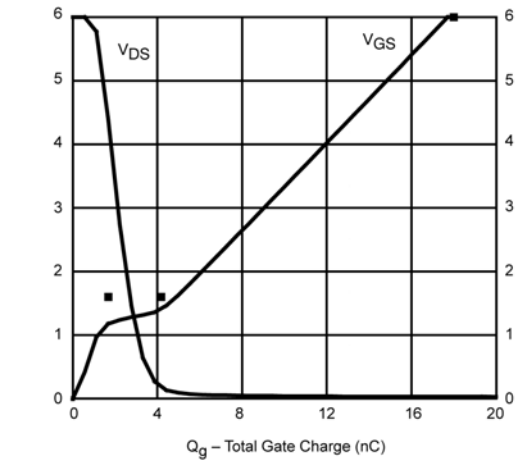












Note: Dots and squares represent measured data.

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